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74VCX16244 Low Voltage 16-Bit Buffer/Line Driver with 3.6V Tolerant Inputs and Outputs

General Description

The VCX16244 contains sixteen non-inverting buffers with 3-STATE outputs to be employed as a memory and address driver, clock driver, or bus oriented transmitter/ receiver. The device is nibble (4-bit) controlled. Each nibble has separate 3-STATE control inputs which can be shorted together for full 16-bit operation.

The 74VCX16244 is designed for low voltage (1.2V to 3.6V) V_{CC} applications with I/O capability up to 3.6V.

The 74VCX16244 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining low CMOS power dissipation.

Features

- 1.2V to 3.6V V_{CC} supply operation
- 3.6V tolerant inputs and outputs
- t_{PD}

2.5 ns max for 3.0V to 3.6V V_{CC}

Power-off high impedance inputs and outputs

October 1996

Revised June 2005

- Supports live insertion and withdrawal (Note 1)
- Static Drive (I_{OH}/I_{OL}) ±24 mA @ 3.0V V_{CC}
- Uses proprietary noise/EMI reduction circuitry
- Latch-up performance exceeds 300 mA
- ESD performance:
 - Human body model > 2000V Machine model > 200V
- Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA)

Note 1: To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pull-up resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

Ordering Code:

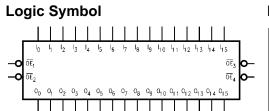
Order Number	Package Number	Package Description
74VCX16244G (Note 2)(Note 3)	BGA54A	54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide
74VCX16244MTD (Note 3)	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide

Note 2: Ordering Code "G" indicates Tray.

Note 3: Devices also available in Tape and Reel. Specify by appending the suffix letter "X" to the ordering code.

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74VCX16244

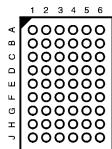


Connection Diagrams

Pin Assignment for TSSOP



Pin Assignment for FBGA



(Top Thru View)

Pin Descriptions

Pin Names	Description
<u>OE</u> n	Output Enable Input (Active LOW)
I ₀ —I ₁₅	Inputs
I ₀ I ₁₅ O ₀ O ₁₅	Outputs
NC	No Connect

FBGA Pin Assignments

	1	2	3	4	5	6
Α	O ₀	NC	OE ₁	$\overline{\text{OE}}_2$	NC	I ₀
В	O ₂	0 ₁	NC	NC	I ₁	l ₂
С	O ₄	O ₃	V _{CC}	V _{CC}	I ₃	I ₄
D	0 ₆	0 ₅	GND	GND	۱ ₅	I ₆
Е	O ₈	0 ₇	GND	GND	I ₇	l ₈
F	O ₁₀	O ₉	GND	GND	l ₉	I ₁₀
G	0 ₁₂	0 ₁₁	V _{CC}	V _{CC}	I ₁₁	I ₁₂
Н	O ₁₄	O ₁₃	NC	NC	I ₁₃	I ₁₄
J	0 ₁₅	NC	\overline{OE}_4	OE ₃	NC	I ₁₅

Truth Tables

Inp	outs	Outputs
OE ₁	I ₀ –I ₃	0 ₀ –0 ₃
L	L	L
L	Н	н
н	Х	Z
Inp	outs	Outputs
OE ₃	I ₈ -I ₁₁	0 ₈ –0 ₁₁
L	L	L
L	Н	н
Н	Х	Z
Inputs		Outputs
OE ₂	I ₄ -I ₇	O ₄ -O ₇
L	L	L
L	Н	н
Н	Х	Z
Inputs		Outputs
OE ₄	I ₁₂ -I ₁₅	O ₁₂ -O ₁₅
L	L	L
L	Н	н
н	х	Z

L = HIGH Voltage Level L = LOW Voltage Level X = Immaterial (HIGH or LOW, inputs may not float) Z = High Impedance

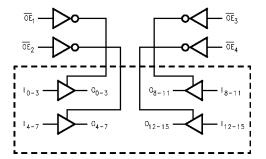
Functional Description

The 74VCX16244 contains sixteen non-inverting buffers with 3-STATE outputs. The device is nibble (4 bits) controlled with each nibble functioning identically, but independent of each other. The control pins may be shorted together to obtain full 16-bit operation. The 3-STATE out-

Logic Diagram

puts are controlled by an Output Enable (\overline{OE}_n) input. When \overline{OE}_n is LOW, the outputs are in the 2-state mode. When \overline{OE}_n is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the inputs.

74VCX16244



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Absolute Maximum Ratings(Note 4)

Supply Voltage (V _{CC})	-0.5V to +4.6V	
DC Input Voltage (VI)	-0.5V to +4.6V	
Output Voltage (V _O)		
Outputs 3-STATED	-0.5V to +4.6V	
Outputs Active (Note 5)	–0.5V to V _{CC} +0.5V	
DC Input Diode Current (I_{IK}) $V_I < 0V$	–50 mA	
DC Output Diode Current (I _{OK})		
$V_{O} < 0V$	–50 mA	
$V_{O} > V_{CC}$	+50 mA	
DC Output Source/Sink Current		
(I _{OH} /I _{OL})	±50 mA	
DC V _{CC} or GND Current per		
Supply Pin (I _{CC} or GND)	±100 mA	
Storage Temperature Range (T _{STG})	-65°C to +150°C	

Recommended Operating Conditions (Note 6)

Power Supply	
Operating	1.2V to 3.6V
Input Voltage	-0.3V to +3.6V
Output Voltage (V _O)	
Output in Active States	0.0V to V_{CC}
Output in 3-State	0.0V to 3.6V
Output Current in I _{OH} /I _{OL}	
V _{CC} = 3.0V to 3.6V	±24 mA
$V_{CC} = 2.3V$ to 2.7V	±18 mA
V _{CC} = 1.65V to 2.3V	±6 mA
V _{CC} = 1.4V to 1.6V	±2 mA
V _{CC} = 1.2V	±100 μA
Free Air Operating Temperature (T _A)	-40°C to +85°C
Minimum Input Edge Rote (At/A)/	

Minimum Input Edge Rate (\(\Delta t/\(\Delta V))

$V_{IN} = 0.8V$ to 2.0V, $V_{CC} = 3.0V$ 10 ns/V

Note 4: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 5: I_O Absolute Maximum Rating must be observed.

Note 6: Floating or unused inputs must be held HIGH or LOW.

DC Electrical	Characteristics
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Symbol	Parameter	Conditions	V _{CC} (V)	Min	Max	Units
VIH	HIGH Level Input Voltage		2.7 - 3.6	2.0		
			2.3 - 2.7	1.6		
			1.65 - 2.3	$0.65 \times V_{CC}$		V
			1.4 - 1.6	$0.65\timesV_{CC}$		
			1.2	$0.65 \times V_{CC}$		
VIL	LOW Level Input Voltage		2.7 - 3.6		0.8	
			2.3 - 2.7		0.7	
			1.65 - 2.3		$0.35 \times V_{CC}$	V
			1.4 - 1.6		$0.35 \times V_{CC}$	
			1.2		$0.05 \times V_{CC}$	
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.7 - 3.6	V _{CC} - 0.2		
		$I_{OH} = -12 \text{ mA}$	2.7	2.2		
		I _{OH} = -18 mA	3.0	2.4		
		$I_{OH} = -24 \text{ mA}$	3.0	2.2		
		$I_{OH} = -100 \ \mu A$	2.3 - 2.7	V _{CC} - 0.2		
		$I_{OH} = -6 \text{ mA}$	2.3	2.0		
		$I_{OH} = -12 \text{ mA}$	2.3	1.8		V
		$I_{OH} = -18 \text{ mA}$	2.3	1.7		
		$I_{OH} = -100 \ \mu A$	1.65 - 2.3	V _{CC} - 0.2		
		$I_{OH} = -6 \text{ mA}$	1.65	1.25		
		$I_{OH} = -100 \ \mu A$	1.4 - 1.6	V _{CC} - 0.2		
		$I_{OH} = -2 \text{ mA}$	1.4	1.05		
		I _{OH} = -100 μA	1.2	V _{CC} - 0.2		

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Symbol	Parameter	Conditions	V _{cc} (V)	Min	Max	Units
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.7 - 3.6		0.2	
		$I_{OL} = 12 \text{ mA}$	2.7		0.4	
		I _{OL} = 18 mA	3.0		0.4	
		$I_{OL} = 24 \text{ mA}$	3.0		0.55	
		I _{OL} = 100 μA	2.3 - 2.7		0.2	
		I _{OL} = 12 mA	2.3		0.4	v
		I _{OL} = 18 mA	2.3		0.6	v
		I _{OL} = 100 μA	1.65 - 2.3		0.2	
		I _{OL} = 6 mA	1.65		0.3	
		I _{OL} = 100 μA	1.4 - 1.6		0.2	
		I _{OL} = 2 mA	1.4		0.35	
		$I_{OL} = 100 \ \mu A$	1.2		0.05	
l _l	Input Leakage Current	$0 \leq V_l \leq 3.6V$	1.2 - 3.6		±5.0	μA
l _{oz}	3-STATE Output Leakage	$0 \leq V_O \leq 3.6V$	1.2 - 3.6		±10.0	μA
		$V_I = V_{IH} \text{ or } V_{IL}$	1.2 - 3.0		±10.0	μΑ
I _{OFF} I	Power-OFF Leakage Current	$0 \leq (V_I, V_O) \leq 3.6V$	0		10.0	μA
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	1.2 - 3.6		20.0	
		$V_{CC} \leq (V_I, V_O) \leq 3.6V \text{ (Note 7)}$	1.2 - 3.6		±20.0	μA
Δl _{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.7 - 3.6		750	μA

AC Electrical Characteristics (Note 8)

Symbol	Parameter	Conditions	V _{CC}	$T_A = -40^{\circ}$	C to +85°C	Units	Figure
Oymbol	raidificter	Conditiona	(V)	Min Max	Onits	Number	
t _{PHL}	Propagation Delay	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$\textbf{3.3}\pm\textbf{0.3}$	0.8	2.5		_
t _{PLH}			$\textbf{2.5}\pm\textbf{0.2}$	1.0	3.0	1, 2	
			1.8 ± 0.15	1.5	6.0		., _
		$C_L = 15 \text{ pF}, \text{ R}_L = 2k\Omega$	1.5 ± 0.1	1.0	12.0		Figures
			1.2	1.5	30.0		5, 6
t _{PZL}	Output Enable Time	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$\textbf{3.3}\pm\textbf{0.3}$	0.8	3.5		E
t _{PZH}			2.5 ± 0.2	1.0	4.1		Figures 1, 3, 4
			1.8 ± 0.15	1.5	8.2	ns	., ., .
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1	1.0	16.4		Figures
			1.2	1.5	41.0		5, 7, 8
t _{PLZ}	Output Disable Time	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$\textbf{3.3}\pm\textbf{0.3}$	0.8	3.5		
t _{PHZ}			2.5 ± 0.2	1.0	3.8		Figures 1, 3, 4
			1.8 ± 0.15	1.5	6.8	ns	, -,
		$C_L = 15 \text{ pF}, \text{ R}_L = 2k\Omega$	1.5 ± 0.1	1.0	13.6		Figures
			1.2	1.5	34.0		5, 7, 8
t _{OSHL}	Output to Output Skew	$C_L = 30 \text{ pF}, R_L = 500\Omega$	$\textbf{3.3}\pm\textbf{0.3}$		0.5		
t _{OSLH}	(Note 9)		2.5 ± 0.2		0.5		
			1.8 ± 0.15		0.75	ns	
		$C_L = 15 \text{ pF}, R_L = 2k\Omega$	1.5 ± 0.1		1.5		
			1.2		1.5		

Note 8: For $C_L = 50_P F$, add approximately 300 ps to the AC maximum specification.

Note 9: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}).

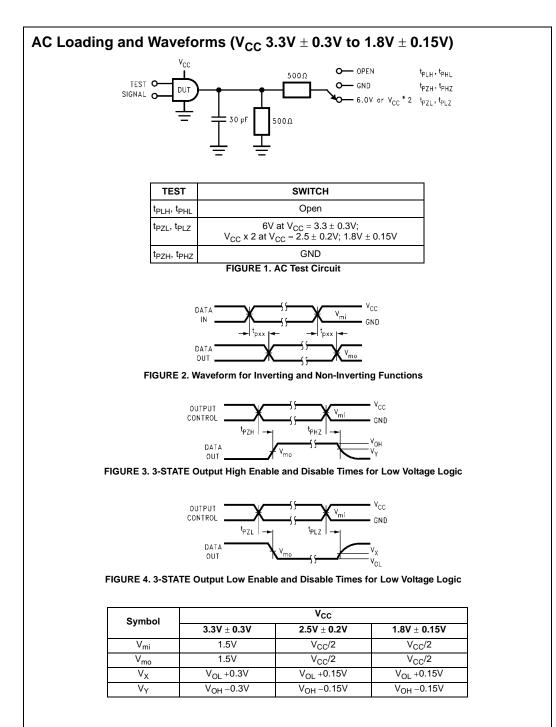
6244	
CX1	
74V	

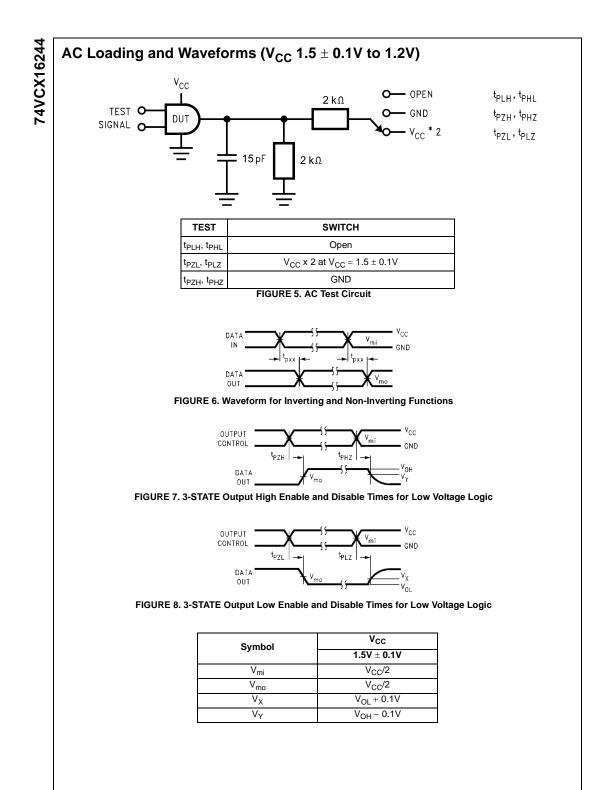
Dynamic Switching Characteristics

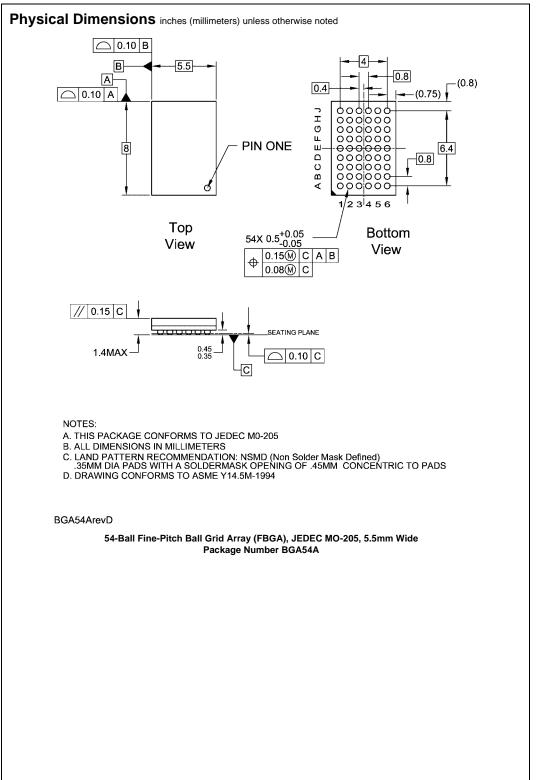
Symbol	Parameter	Conditions	V _{cc}	$\textbf{T}_{\textbf{A}}=+25^{\circ}\textbf{C}$	Units
Gymbol	Falameter	Conditions	(V)	Typical	onits
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	0.25	
			2.5	0.6	V
			3.3	0.8	
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	-0.25	
			2.5	-0.6	V
			3.3	-0.8	
V _{OHV}	Quiet Output Dynamic Valley V _{OH}	$C_L = 30 \text{ pF}, V_{IH} = V_{CC}, V_{IL} = 0V$	1.8	1.5	
			2.5	1.9	V
			3.3	2.2	

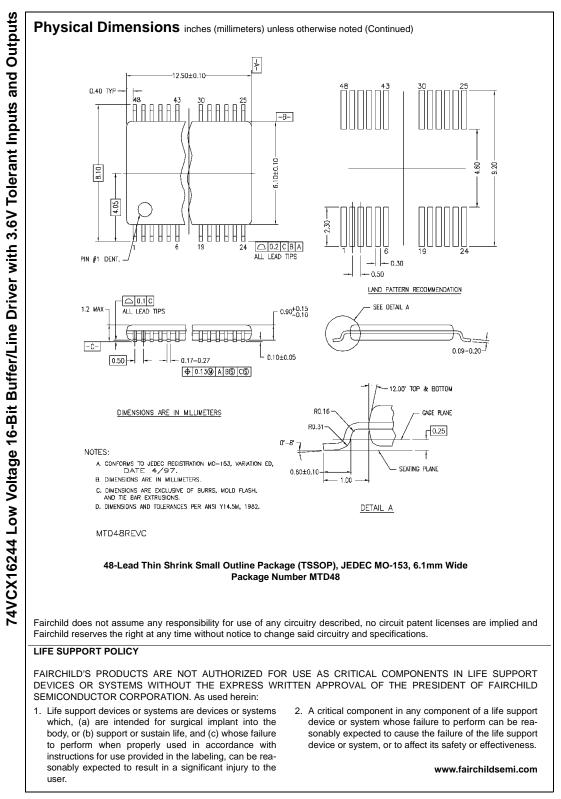
Capacitance

Symbol	Parameter	Conditions	$T_A = +25^{\circ}C$	Units
			Typical	
CIN	Input Capacitance	V_{CC} = 1.8, 2.5V or 3.3V, V_I = 0V or V_{CC}	6.0	pF
C _{OUT}	Output Capacitance	$V_I = 0V \text{ or } V_{CC}, V_{CC} = 1.8V, 2.5V \text{ or } 3.3V$	7.0	pF
C _{PD}	Power Dissipation Capacitance	V_{I} = 0V or V_{CC},f = 10 MHz, V_{CC} = 1.8V, 2.5V or 3.3V	20.0	pF









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